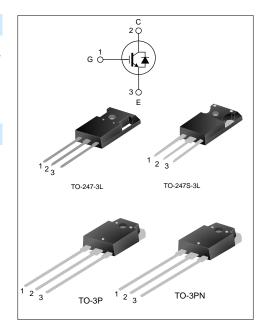
60A, 600V FIELD STOP IGBT

DESCRIPTION

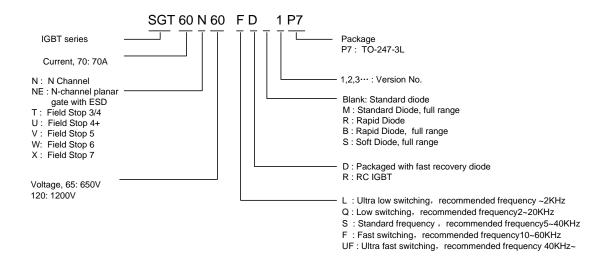
SGT60N60FD1PN/P7/PS/PT adopts Field Stop IGBT technology, offer the optimum performance for induction Heating, UPS, SMPS and PFC application.

FEATURES

- 60A, 600V, $V_{CE(sat)(typ.)}$ =2.2V@ I_C =60A
- Low conduction loss
- Fast switching
- High input impedance



NOMENCLATURE



ORDERING INFORMATION

Part No.	Package	Marking	Hazardous Substance Control	Packing Type
SGT60N60FD1PN	TO-3P	60N60FD1	Pb free	Tube
SGT60N60FD1P7	TO-247-3L	60N60FD1	Pb free	Tube
SGT60N60FD1PS	TO-247S-3L	60N60D1	Pb free	Tube
SGT60N60FD1PT	TO-3PN	60N60FD1	Pb free	Tube

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ABSOLUTE MAXIMUM RATINGS (Tc = 25°C UNLESS OTHERWISE NOTED)

Characteristics		Symbol	Ratings	Units	
Collector to Emitter Voltage		V _{CE}	600	V	
Gate to Emitter Voltage		V_{GE}	±20	V	
Collector Current	T _C =25°C	ı	120	А	
Collector Current	T _C =100°C	I _C	60		
Pulsed Collector Current		I _{CM}	180	Α	
Maximum Power Dissipation (T _C =25°C)		P _D	321	W	
Operating Junction Temperature		TJ	-55∼+175	°C	
Storage Temperature Range		T _{stg}	-55∼+175	°C	

THERMAL CHARACTERISTICS

Characteristics	Symbol	Ratings	Units
Thermal Resistance, Junction to Case(IGBT)(TO-3P)	$R_{ heta JC}$	0.39	°C/W
Thermal Resistance, Junction to Case(FRD)(TO-3P)	$R_{ heta JC}$	1.10	°C/W
Thermal Resistance, Junction to Ambient(TO-3P)	R _{0JA}	40	°C/W

ELECTRICAL CHARACTERISTICS OF IGBT(T_C=25°C, UNLESS OTHERWISE NOTED)

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Units
Collector to Emitter Breakdown Voltage	BV _{CE}	V _{GE} =0V,I _C =250uA	600			V
C-E Leakage Current	I _{CES}	V _{CE} =600V,V _{GE} =0V			200	μA
G-E Leakage Current	I _{GES}	V _{GE} =20V,V _{CE} =0V			±400	nA
G-E Threshold Voltage	V _{GE(th)}	I _C =250uA,V _{CE} =V _{GE}	4.0	5.0	6.5	V
Collector to Emitter	V	I _C =60A,V _{GE} =15V		2.2	2.7	V
Saturation Voltage	$V_{CE(sat)}$	I _C =60A,V _{GE} =15V,T _C =125°C		2.6		V
Input Capacitance	C _{ies}	V _{CE} =30V		2850		
Output Capacitance	C _{oes}	V _{GE} =0V		294		pF
Reverse Transfer Capacitance	C _{res}	f=1MHz		85		
Turn-On Delay Time	T _{d(on)}			36		
Rise Time	T _r	V _{CE} =400V		142		
Turn-Off Delay Time	$T_{d(off)}$	I _C =60A		193		ns
Fall Time	T _f	$R_g=10\Omega$		136		
Turn-On Switching Loss	E _{on}	V _{GE} =15V		3.72		
Turn-Off Switching Loss	E _{off}	Inductive Load,		1.77		mJ
Total Switching Loss	E _{st}			5.49		
Total Gate Charge	Q_g	\/ 400\/ L 00A		179		
Gate to Emitter Charge	Q_{ge}	V _{CE} =400V,I _C =60A,		23		nC
Gate to Collector Charge	Q_{gc}	V _{GE} =15V		100		

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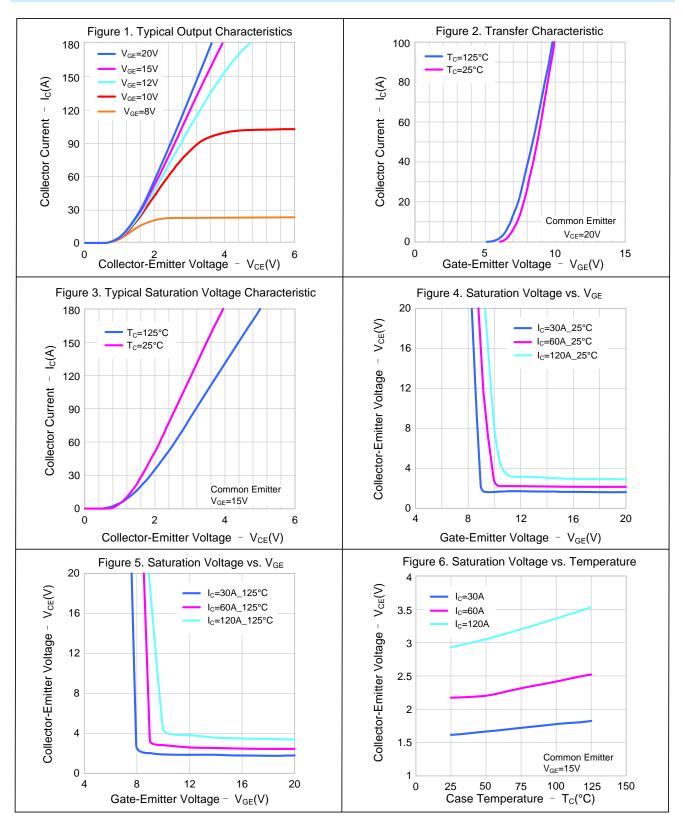
ELECTRICAL CHARACTERISTICS OF FRD(Tc=25°C UNLESS OTHERWISE NOTED)

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Units	
Diada Farmard Valtage	\/	I _F =30A,T _C =25°C		1.9	2.6	.,	
Diode Forward Voltage	V_{FM}	I _F =30A,T _C =125°C		1.5		V	
Diode Reverse Recovery Time	T _{rr}	I _{ES} =30A,dI _{ES} /dt=200A/μs		38		ns	
Diode Reverse Recovery Charge	Q _{rr}	I _{ES} =30A,dI _{ES} /dt=200A/µs		85		nC	

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TYPICAL CHARACTERISTICS CURVE

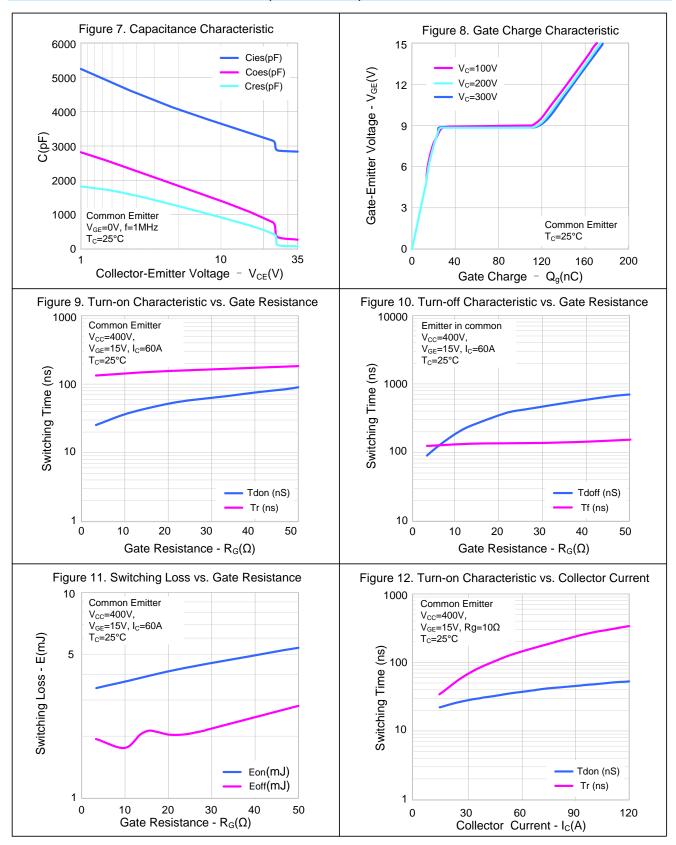


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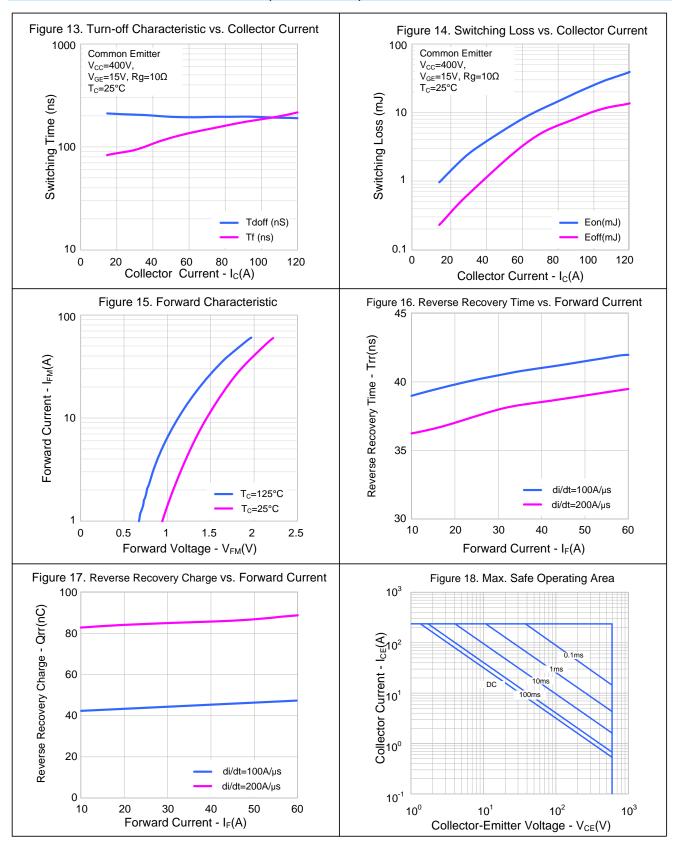
TYPICAL CHARACTERISTICS CURVE (CONTINUED)



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TYPICAL CHARACTERISTICS CURVE (CONTINUED)

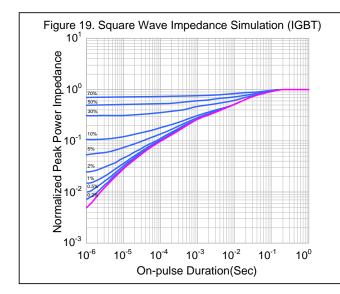


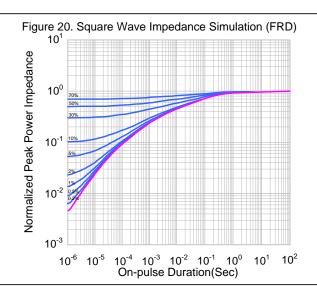
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TYPICAL CHARACTERISTICS CURVE (CONTINUED)

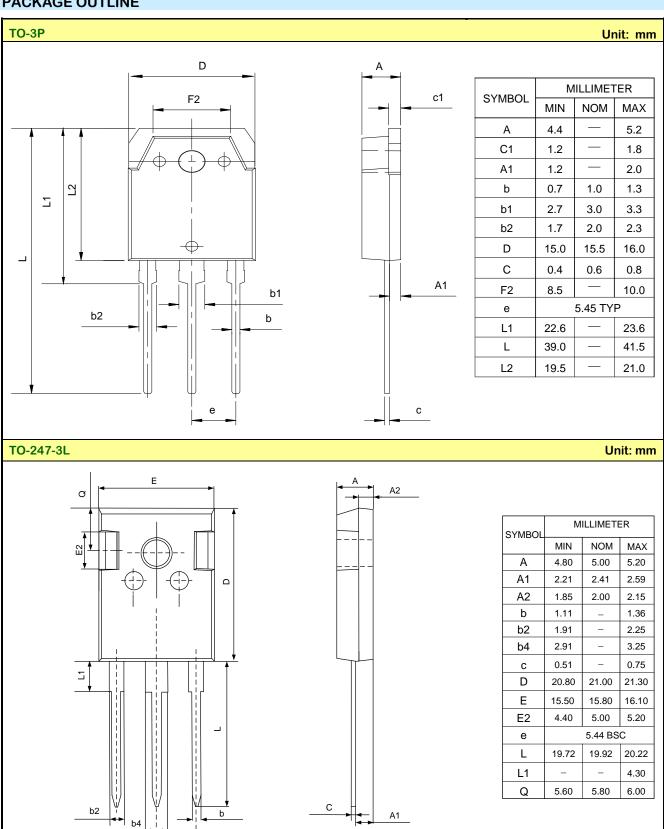




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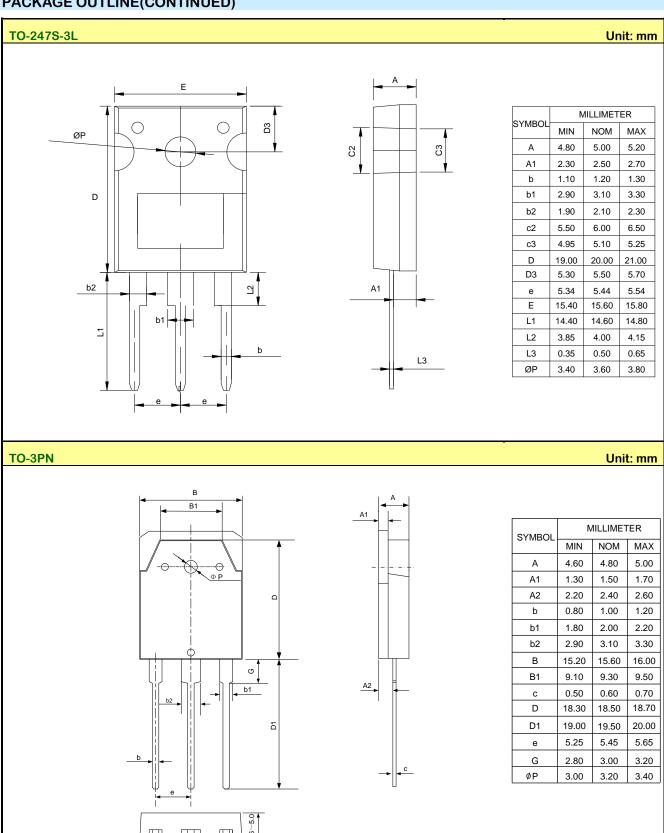
PACKAGE OUTLINE



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PACKAGE OUTLINE(CONTINUED)



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 machine will be affected. There is a certain possibility of failure or malfunction of any semiconductor product under specific
 conditions. The buyer is responsible for complying with safety standards and taking safety measures when using our products
 for system design, sample and whole machine manufacturing, so as to avoid potential failure risk that may cause personal
 injury or property loss.
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- When exporting, using and reselling our products, buyer must comply with the international export control laws and regulations of China, the United States, the United Kingdom, the European Union and other countries & regions.
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